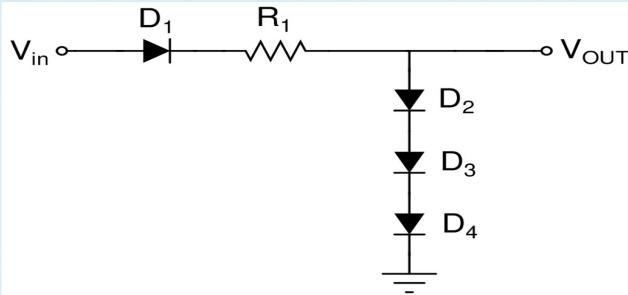


## Tutorial\_1 solution

In the figure below, assume each diode has a cut-in voltage of 0.8V and  $R_1 = 4700 \Omega$ . If the input voltage  $V_{in}$  is changed from 5V to 5.1V determine the corresponding change in the  $V_{out}$  (in mV). (Take  $V_T = 26mV$ , Give answer up to at least 3 decimal places).



Ans -

Applying KVL

$$I = \frac{5 - (4 \times 0.8)}{4700}$$

$$I = 0.3829 \text{ mA}$$

Diode small signal resistance ( $r_d$ ) =  $\frac{V_T}{I} \Omega$

Change in o/p voltage

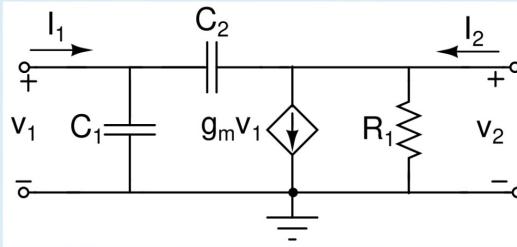
$$\Delta V_{out} = \frac{3r_d}{3r_d + R + r_d} \Delta V_{in}$$

$$= 4.09 \text{ V}$$

Ans = 4.09 V

# Note as the  $R_1 \gg r_d$ , so small signal approximation valid here.

For the given 2-port network, shown in the figure, calculate the magnitude of  $y_{21}$ . The operating frequency is kept at 220 MHz. Use  $C_1 = 1 \mu\text{F}$ ,  $C_2 = 2 \mu\text{F}$ ,  $g_m = 100 \text{ mS}$ ,  $R_1 = 260 \Omega$ .



(Give answer up to at least 3 decimal places)

Ans :-  $\frac{I_2}{V_1} = \frac{I_2}{V_1} \Big|_{V_2=0}$

Short the  $V_2$  and applying KCL at the open node

$$I_2 = g_m V_1 - s C_2 V_1$$

$$\frac{I_2}{V_1} = g_m - s C_2$$

$$y_{21} = \sqrt{g_m^2 + (2\pi f C_2)^2}$$

$$y_{21} = \sqrt{(0.01)^2 + (2 \times 3.14 \times 220 \times 10^6 \times 2 \times 10^{-6})^2}$$

$y_{21} = 2763.200$

A small signal peak to peak current at a level of 2.7% of  $I_{DQ}$ , the quiescent bias current, is applied to a forward biased PN junction diode. If the DC bias current is kept at 2.5 mA, then the small signal peak to peak output voltage swing obtained (in mV) is: (Take  $V_T = 26\text{mV}$ )

Ans :-

$$\text{Signal current level } (id) = \frac{2.7 \times I_{DQ}}{100}$$

Small signal diode resistance

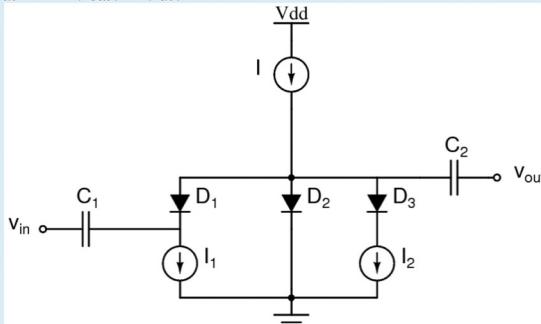
$$r_d = \frac{V_T}{I_D}$$

$V_T$  = thermal voltage  
 $I_D$  = DC bias current

$$\begin{aligned} \text{Voltage swing} &= V_d = id r_d \\ &= \frac{2.7 \times 26\text{mV}}{100} \\ &= 0.702\text{mV} \end{aligned}$$

Ans = 0.702 mV

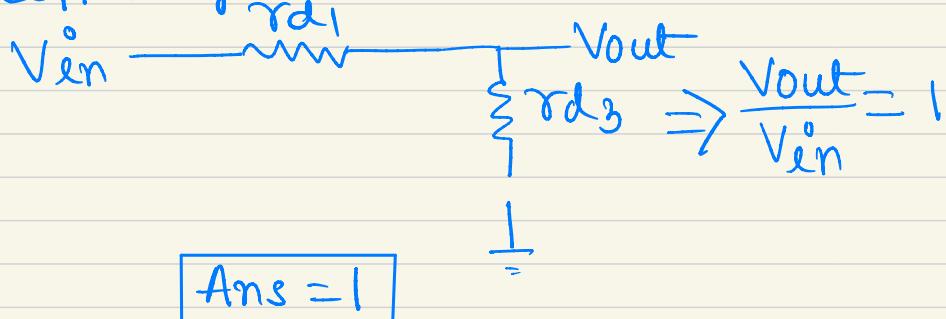
In the circuit shown below,  $I = 500 \mu\text{A}$  and  $I_1 = 167 \mu\text{A}$ ,  $I_2 = 333 \mu\text{A}$ .  $C_1$  and  $C_2$  are large coupling capacitors. For small signal input  $v_{in}$ , Find  $(v_{out}) / (v_{in})$



Ans :-

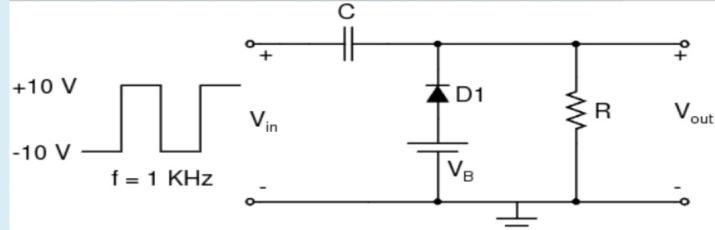
$$\text{As, } I = I_1 + I_2,$$

$D_1 \times D_2$  are turned on,  $D_2$  is turned off  
For small signal analysis current sources will be off as they are DC.



# Note for dc capacitors acts as an open circuit & for small signal acts as a short circuit.

Find the maximum value of  $V_{out}$  (in Volts) in the circuit given below for  $V_B = 5$  V,  $R = 24.3 \text{ k}\Omega$  and  $C = 1 \mu\text{F}$ . Assume voltage drop across D1 to be 0.7 V when it is ON.



Ans :

When  $V_{in} = -10$  V, D1 is ON.  
The voltage stored in cap C,  
 $V_C = [5 - 0.7 - (-10)]$  V

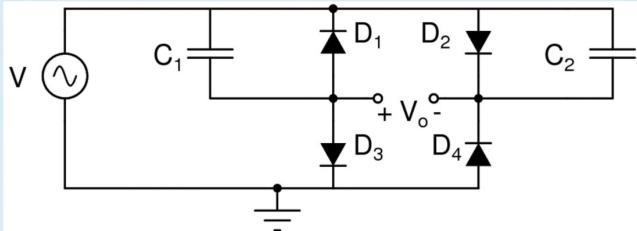
$$V_C = 14.3 \text{ V}$$

When  $V_{in} = 10$  V, D1 is OFF

$$\begin{aligned} \text{So, } V_{out} &= (10 + V_C) \text{ V} \\ &= (10 + 14.3) \text{ V} \\ &= 24.3 \text{ V} \end{aligned}$$

Ans = 24.3 V

In the circuit shown below  $V = V_m \sin(6283t)$  where  $V_m = 5$  V,  $C_1 = 6 \mu\text{F}$ ,  $C_2 = 3 \mu\text{F}$ . Find  $V_o$  at steady state in Volts. (Assume diode cut in voltage as 0.7 V)



Ans.

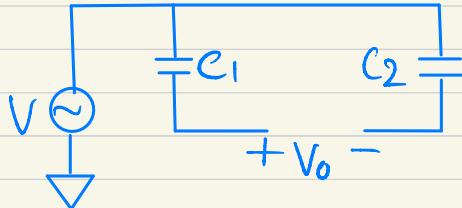
In the positive half cycle,  $D_3$  will be FB,  $D_1$ ,  $D_2$ , &  $D_4$  are RB.

The voltage stored in the  $C_1 = (5 - 0.7) \text{ V}$   
 $= 4.3 \text{ V}$

In the negative half cycle,  $D_4$  will be FB,  $D_1$ ,  $D_2$ , &  $D_3$  are RB.

The voltage stored in the  $C_2 = -(5 - 0.7) \text{ V}$   
 $= -4.3 \text{ V}$

At steady state,  $D_1$ ,  $D_2$ ,  $D_3$ ,  $D_4$  will be R.B.



If we apply KVL,

$$V_o = (-4.3 - 4.3) \text{ V}$$

$$= -8.6 \text{ V}$$

Ans =  $-8.6 \text{ V}$

Consider a nonlinear amplifier with input output characteristics  $V_{out} = V_A \exp(V_{in}/V_A)$ , Where  $V_A = 144$  mV. To achieve small signal gain of 30, find out the upper limit of input (in mV) for which small signal approximation is valid? (Assume first order term is greater than second order term)

Ans :-

Small signal approximation,

$$\Delta V_{out} + V_{out} = f(V_{in} + \Delta V_{in})$$

$$= f(V_{in}) + \Delta V_{in} f'(V_{in}) + \frac{\Delta V_{in}^2}{2!} f''(V_{in}) + \dots \text{higher order terms}$$

For small signal approximation to be valid

$$\Delta V_{in} f'(V_{in}) > \frac{\Delta V_{in}^2}{2} f''(V_{in})$$

$$\Rightarrow \Delta V_{in} < \frac{2 f'(V_{in})}{f''(V_{in})} \quad \dots (1)$$

$$f'(V_{in}) = \exp\left(\frac{V_{in}}{V_A}\right), \quad f''(V_{in}) = \frac{1}{V_A} \exp\left(\frac{V_{in}}{V_A}\right)$$

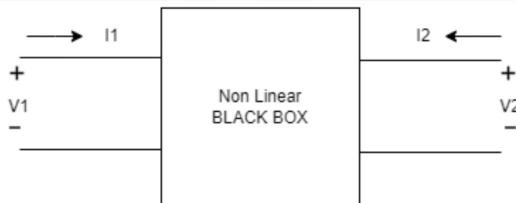
From (1)

$$\Delta V_{in} < \frac{2 \exp\left(\frac{V_{in}}{V_A}\right)}{\frac{1}{V_A} \exp\left(\frac{V_{in}}{V_A}\right)}$$

$$\Delta V_{in} < 2 V_A$$

$\text{Ans} = 244 \text{ mV}$

A certain non-linear device has the following output current expression:



$$I_2 = I_0 e^{V_1/V_T} (1 - e^{-V_2/V_T})$$

Find the linear small signal approximated y-parameter corresponding to the device transconductance (in S). Take  $V_1 = 520\text{mV}$ ,  $V_2 = 260\text{mV}$ ,  $I_0 = 4 \times 10^{-10} \text{ A}$ . (Take  $V_T = 0.026\text{V}$ )  
(Give answer up to at least 3 decimal places)

Ans :-

Transconductance is given by change in o/p current due to a differential change in the i/p voltage.

$$\text{As, } y_{21} = \frac{dI_2}{dV_1}$$

So,  $y_{21}$  is the transconductance

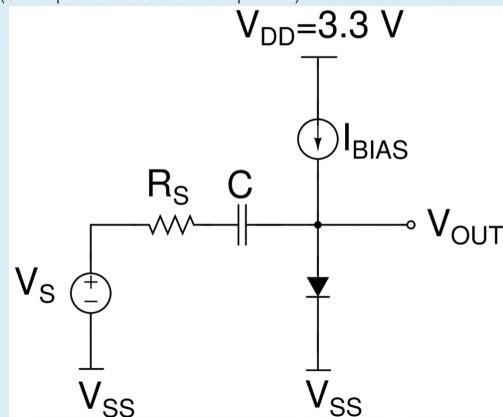
$$I_2 = I_0 e^{V_1/V_T} (1 - e^{-V_2/V_T})$$

$$\frac{dI_2}{dV_1} = \frac{d}{dV_1} [I_0 e^{V_1/V_T} (1 - e^{-V_2/V_T})]$$

$$= I_0 \left[ e^{20} \left( 1 - e^{-10} \right) \right]$$

$$\boxed{\text{Ans} = 7.456}$$

Consider a diode biased by  $I_{BIAS} = 3 \mu A$ . A small signal with source impedance  $R_S = 900 \Omega$  is coupled to the Q-point using a large capacitor  $C$ . Find the small signal voltage gain  $V_{OUT}/V_s$ . (Give upto at least 3 decimal places.)



Ans

In dc, C will be acts as open circuit  
So, vs small signal resistance

$$r_{sd} = \frac{V_T}{I_{BIAS}}$$

In the vs small signal equivalent, C can be replaced with a short cpt

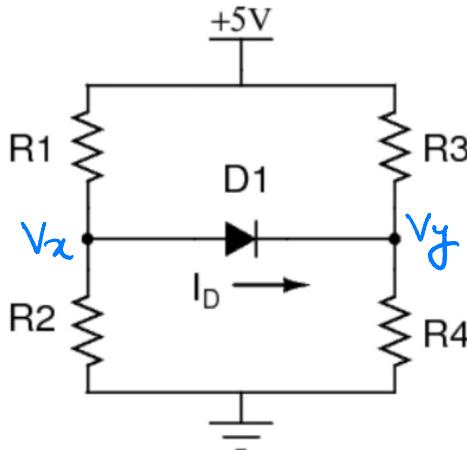
$$V_o = \left[ \frac{r_{sd}}{r_{sd} + R_S} \right] V_s$$

So, vs small signal gain.

$$\begin{aligned} \frac{V_o}{V_s} &= \frac{\frac{V_T}{I_{BIAS} R_S}}{V_T + I_{BIAS} R_S} \\ &= \frac{0.026}{0.026 + (3 \times 10^{-6}) \times (900)} \end{aligned}$$

$$\boxed{AV = 0.9059}$$

The circuit below contains resistors and a diode. If  $R_1$ ,  $R_2$ ,  $R_3$  and  $R_4$  are  $2.2\text{ k}\Omega$ ,  $8.8\text{ k}\Omega$ ,  $6.6\text{ k}\Omega$  and  $4.4\text{ k}\Omega$  respectively, find the operating current  $I_D$  through diode  $D_1$  (in milli-amperes). Assume voltage drop across  $D_1$  to be  $0.7\text{ V}$  when it is ON. (Give answer upto 3 decimal places).



Ans :-

Assuming  $D_1$  is off

$$V_x = \frac{5 \times 8.8}{2.2 + 8.8} = 4\text{ V}$$

$$V_y = \frac{5 \times 4.4}{8.8 + 4.4} = 2\text{ V}$$

$V_x > V_y \rightarrow D_1$  is On

[Initial assumption was wrong]

Now if  $D_1$  is on,

$$\frac{V_x}{8.8} + \frac{V_x - 5}{2.2} + I_D = 0 \quad \dots (1)$$

$$\frac{V_y}{4.4} + \frac{V_y - 5}{6.6} + I_D = 0 \quad \dots (2)$$

$$V_x - V_y = 0.7 \quad \dots (3)$$

If we solve the eqn(1), eqn(2) & eqn(3)

$$\text{We get, } V_x = 3.48V$$

$$V_y = 2.78V$$

Now again,

$$I_D = \frac{5 - 3.48}{2.2} - \frac{3.48}{8.8}$$

$$I_D = 0.295$$